Structural, optical, and electrical properties of Mg\textsubscript{y}Ti\textsubscript{1−y}H\textsubscript{x} thin films

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The structural, optical, and electrical transformations induced by hydrogen absorption and/or desorption in Mg-Ti thin films prepared by co-sputtering of Mg and Ti are investigated. Highly reflective in the metallic state, the films become highly absorbing upon hydrogen absorption. The reflector-to-absorber transition is fast, robust, and reversible over many cycles. Such a highly absorbing state hints at the coexistence of a metallic and a semiconducting phase. It is, however, not simply a composite material consisting of independent MgH\textsubscript{2} and TiH\textsubscript{2} grains. By continuously monitoring the structure during H uptake, we obtain data that are compatible with a coherent structure. The average structure resembles rutile MgH\textsubscript{2} at high Mg content and is fluorite otherwise. Of crucial importance in preserving the reversibility and the coherence of the system upon hydrogen cycling is the accidental equality of the molar volume of Mg and TiH\textsubscript{2}. The present results point toward a rich and unexpected chemistry of Mg-Ti-H compounds.

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I. INTRODUCTION

Recently, Notten and co-workers\textsuperscript{1,2} reported on the excellent hydrogen storage capacity of Mg-Ti-H thin films which is approximately five times larger than that of conventional metal hydride electrodes in NiMH batteries. Rather surprisingly, we found that the same material has also remarkable optical properties.\textsuperscript{3} Highly reflective in the metallic state, the films become strongly absorbing upon hydrogen absorption. For example, fully hydrogenated Mg\textsubscript{0.80}Ti\textsubscript{0.20}H\textsubscript{1.7} (5.5 wt. % H) thin films combine a high absorption (87% of the solar spectrum) with a low thermal emissivity (only 10%), while after removal of hydrogen Mg\textsubscript{0.80}Ti\textsubscript{0.20} absorbs no more than 1/3 of the solar spectrum. The energy conversion performance of fully hydrogenated Mg\textsubscript{0.80}Ti\textsubscript{0.20}H\textsubscript{1.7} is comparable to those of advanced solar coatings such as alloyed bulk samples\textsuperscript{6} and in thin films.\textsuperscript{7}

II. EXPERIMENT

Mg\textsubscript{y}Ti\textsubscript{1−y} thin films are prepared by dc and/or rf magnetron co-sputtering of Mg and Ti on quartz substrates. Various compositions in the 0.55 < y < 0.95 range are studied. Typical deposition rates are 2 Å/s for Mg (150 W rf power), 0.1–1 Å/s for Ti (25–160 W dc power), and 1.3 Å/s for Pd (50 W dc power). All the films are covered in situ with a Pd layer (5–10 nm) to prevent oxidation of the Mg-Ti film and to promote dissociation of H\textsubscript{2}.\textsuperscript{10,11} A detailed account of the dissociation mechanism is given by Borgschulte et al.\textsuperscript{11}
mogeneous composition and thickness over the entire substrate area are ensured by continuously rotating the substrates during sputtering. In addition, we prepared Mg$_{y}$Ti$_{1-y}$ (0.55 $< y < 0.95$) gradient thin films to study the concentration dependent properties in a continuous way. The composition of the films is investigated by Rutherford backscattering spectrometry on samples grown in the same deposition run but on carbon substrates. Optical reflection ($R$) and transmission ($T$) spectra are measured simultaneously during hydrogenation (pressures up to 1 bar H$_2$) in a PerkinElmer Lambda 900 diffraction grating spectrometer ($0.495 < h\omega < 6.51$ eV) and a Bruker IFS 66 Fourier transform spectrometer ($0.72 < h\omega < 3.5$ eV). The $R$-$T$ spectra are measured through the transparent substrate at near normal incidence of the incoming beam. As an indication of hydrogen uptake in the films, the electrical resistivity of the films is measured in a van der Pauw configuration together with the $R$-$T$ spectra. The structural properties of the films are investigated by means of x-ray diffraction (XRD) in a Bruker D8 Discover x-ray diffractometer equipped with a two-dimensional (2D) detector which allows real-time data collection over a large area with high speed, high sensitivity, and low background. A Be dome allows in situ x-ray measurements upon hydrogenation. XRD patterns are also measured during de-hydrogenation (in air, at room temperature). The dehydrogenation time (few minutes for a 50 nm Mg$_{0.70}$Ti$_{0.30}$/30 nm Pd film) depends on the thickness of the film and can be improved by decreasing the thickness and/or increasing the temperature. All the measurements are done using the Cu $K\alpha$ radiation ($\lambda = 1.5418$ Å). Additionally, transmission electron microscope (TEM) plan-view and cross-sectional images were recorded using a JEOL 2010F working at 200 kV (point resolution of 0.23 nm and information limit of 0.11 nm). This TEM is also equipped with an energy dispersive x-ray spectrometer and a Gatan imaging filter (GIF 2000). The plan-view samples were obtained by directing the films on silicon nitride membranes (30 nm thick). Hydrogenated samples were prepared using a 1 nm Pd cap layer. Cross-section samples were made by cutting, polishing, and ion milling with 4 kV Ar ions with a Gatan precision ion polishing system. To measure the hydrogen content, electrochemical measurements (loading and/or unloading) are done in a standard three electrode setup containing a Hg/HgO reference electrode and a Pt counter-electrode in a 1M KOH electrolyte. The reflection and the transmission at $\lambda = 635$ nm (1.95 eV) can be measured simultaneously in the electrochemical setup.

III. RESULTS

A. Optical and electrical properties

Hydrogen uptake in Mg$_{y}$Ti$_{1-y}$ thin films is fast and induces a gradual change in optical appearance for all alloy compositions. The color of the fully hydrogenated films changes from dark gray to yellowish with increasing Mg fraction. The kinetics of hydrogen uptake improves with increasing Ti content in the alloy and compositions with only a few percents of Ti are already far superior to pure Mg.

![Reflection and transmission spectra measured on 200 nm Mg$_{y}$Ti$_{1-y}$/10 nm Pd films ($y=0.70$, $y=0.80$, and $y=0.90$) after hydrogenation in 1 bar H$_2$ at room temperature. The solid lines are calculations using a Drude-Lorentz parametrization scheme.](image_url)
absorption coefficient $\alpha$. This is calculated from the $R$-$T$ data measured on thin films and corrected for the Pd cap layer as follows:

$$\alpha = -\frac{1}{d} \left[ \ln \left( \frac{T}{1-R} \right) + \alpha_{Pd} d_{Pd} \right],$$

with $\alpha_{Pd} = 2k\omega/c$, where $k$ is the extinction coefficient of Pd.\textsuperscript{16} The results are shown in Fig. 2(c). For comparison, the absorption coefficient of MgH$_2$ is also shown. All Mg-Ti-H compositions have a similar dependence: an absorption edge at high energies and significant absorption below this edge. An effective band gap $E_g$ is tentatively estimated by linearly extrapolating the absorption edge to zero. This extrapolation is, however, not unique, making the value of $E_g$ only approximate. The dependence of absorption coefficient on energy is also common to other Mg-based systems such as Mg-Pd-H,\textsuperscript{17} Mg-Y-H,\textsuperscript{18} or Mg-Ni-H,\textsuperscript{19} but the mechanism responsible for this effect is often different. Whereas in Mg-Pd-H it was understood by considering Pd as a deep donor in semiconducting MgH$_2$, in Mg-Y-H it was attributed to quantum confinement effects. However, such an absorption edge could be seen as the signature of MgH$_2$ or a phase with a similarly large energy gap.

FIG. 2. (Color online) Optical (a) reflection and (b) transmission spectra measured on 50 nm Mg$_x$Ti$_{1-x}/5$ nm Pd ($y=0.70, 0.80$, and $0.90$) films after hydrogenation in 1 bar H$_2$ at room temperature. (c) Absorption coefficient $\alpha$ for Mg$_x$Ti$_{1-x}/H_y$ ($y=0.70, 0.80, 0.90$, and $1$).

To get a qualitative understanding of the optical properties, we analyze the optical data within the framework of an effective-medium approximation. We assume a two-phase system consisting of a metallic and a dielectric phase. This method was successfully applied previously\textsuperscript{20} to the Mg-MgH$_2$ system to explain that the highly absorbing state found at intermediate hydrogen compositions was due to the coexistence of nanoscale grains of metallic Mg and insulating MgH$_2$ (with a gap $E_g=5.6$ eV). The Bruggeman effective-medium approximation\textsuperscript{21} can be used if the particle size is smaller than the wavelength of light, a criterion generally valid for metal hydride thin films. As a first approximation of the Mg-Ti-H system, we assume a medium consisting of spherical grains of metallic TiH$_2$ and insulating MgH$_2$ [volume fraction $f(MgH_2)$]. The effective dielectric function of such a medium is calculated from the dielectric functions of TiH$_2$ and MgH$_2$, determined in separate runs. Subsequently, the transfer-matrix method\textsuperscript{22} is used to calculate the reflection and transmission of the total sample also taking into account the quartz substrate and a 6 nm PdH$_x$ cap layer.\textsuperscript{16} A comparison with spectra measured on 60 nm Mg$_x$Ti$_{1-x}/H_y/6$ nm PdH$_x$ films is shown in Fig. 3. The $f(MgH_2)$ volume fractions used are 0.75, 0.85, and 0.92 for $y=0.70, 0.80$, and 0.90, respectively. As shown here, the agreement is reasonable below 4 eV, but the calculated data deviate considerably from the measured spectra at high energies. We also considered a nonspherical shape of the grains or even a different effective-medium approximation (e.g., Maxwell-Garnet). In this case, the deviation between the calculated and the measured spectra was even bigger. The failure of an effective-medium approximation to reproduce in detail the measured optical properties indicates a more complex phase composition and/or interaction on an atomic level between the components. However, this analysis indicates unambiguously that the hydrogenated films contain a signifi-
Temperature dependent resistivity measurements done on a thin film to decrease in the number of free carriers in the films. This conclusion is further substantiated by electrical resistivity measurements.

As-prepared films have electrical resistivity ($\rho$) values typical for metals ($50-100 \mu\Omega\ cm$). Upon hydrogenation, $\rho$ increases gradually to final values that are more than a factor of 5 higher than in the as-prepared state. Typical values measured on fully hydrogenated films are $1.32$ and $1.9$ m$\Omega\ cm$ for $y=0.70$ and $y=0.90$ samples, respectively (all the values are corrected for the Pd cap layer by assuming a parallel resistor model and $\rho_{Pd}=0.75 \mu\Omega\ cm$ (Ref. 20)). These values point to a decrease in the number of free carriers in the films. Temperature dependent resistivity measurements done on a 200 nm Mg$_{0.70}$Ti$_{0.30}$/1 nm Pd sample in the fully hydrogenated state are shown in Fig. 4. Such a thin Pd cap layer is sufficient for hydrogenation of the film but consists of disconnected islands. It is thus possible to measure the intrinsic electrical resistivity of the Mg-Ti layer. Upon cooling, the electrical resistivity increases, pointing to a nonmetallic behavior. The logarithmic temperature dependence of the resistivity in the range of 35 K $\leq T < 298$ K is similar to that reported for granular niobium nitride cermet films. A similar dependence was also reported for YH$_{1-x}$ (Ref. 24) and discussed in terms of 2D weak electron localization or Kondo scattering. Although the microscopic origin of the log $T$ dependence in Fig. 4 has not been identified yet, the data imply clearly that Mg$_{0.70}$Ti$_{0.30}$H$_{1.55}$ is neither a metal nor a semimetal.

The hydrogen concentration dependence of the optical properties can be obtained from measurements in an optical-electrochemical cell. In this case, reflection and transmission at 1.95 eV are measured simultaneously with the hydrogen content. The results obtained for a 100 nm Mg$_{0.70}$Ti$_{0.30}$/10 nm Pd film in a constant current mode ($I=-133.3 \mu A/cm^2$) are shown in Fig. 5. With increasing amount of hydrogen in the sample, the reflection decreases while the transmission increases gradually. Such a behavior is typical for a homogeneous nucleation and growth of a hydride phase within the whole volume of the sample as was observed in Mg-MgH$_2$ thin films. For [H]/[M] $< 0.5$ (dashed line in Fig. 5), the measured transmission falls below the detection limit of the instrument. Above [H]/[M] $> 0.5$, the logarithm of the transmission increases linearly as expected from Lambert-Beers’s law. The total amount of hydrogen that can be incorporated is [H]/[M] $\sim 1.55$. This value is below the theoretical limit of [H]/[M]=2 expected for an alloy of two metals forming the dihydrides TiH$_2$ and MgH$_2$. Our results are in agreement with the results of Vermuelen et al. measured on $e$-beam deposited thin films. They moreover showed that the H content in the fully hydrogenated state decreases with increasing the amount of Ti for all alloy compositions measured.

**B. Structural properties**

Structural data obtained from x-ray diffraction measurements are summarized in Fig. 6. X-ray $\theta$-$2\theta$ scans measured on $y=0.70$ and $y=0.90$ samples are shown in Figs. 6(a) and 6(b), respectively. Here, we compare spectra corresponding to the as-prepared (initial), fully hydrogenated (at room temperature in 1 bar H$_2$), and dehydrogenated (after exposure to air) states.

In the XRD spectra, there are reflections from the Mg-Ti layer and from the Pd cap layer. The peak at $\sim 40.1^\circ$ corresponds to the (111) reflection of Pd. Upon hydrogenation, the peak shifts to lower scattering angles, indicating thus the formation of PdH$_x$. The reflection of Pd is absent for samples with a composition $y=0.90$, even though the presence of Pd was confirmed by Rutherford backscattering spectroscopy. A similar result was obtained for $e$-beam deposited Mg-Ti films or pure Mg films. Therefore, on Mg-rich surfaces, the Pd appears not to have a preferential orientation, which is necessary for these thin films to produce an XRD reflection. Very likely, this is related to the morphology of the Mg-Ti and Mg layers.

For as-prepared $y=0.70$ and $y=0.90$ samples [Figs. 6(a) and 6(b)], there is only one reflection peak that is assigned to...
The Mg-Ti layer. The $2\theta$ position of this peak depends on the Mg/Ti ratio and is between the (002) reflection of Mg ($2\theta = 34.4^\circ$; hexagonal structure) and the (002) reflection of Ti ($2\theta = 38.52^\circ$; hexagonal structure). This suggests the formation of a Mg-Ti random alloy on deposition with the same hexagonal symmetry as the metal constituents. The formation of a random alloy is, however, highly unlikely given the large positive enthalpy of mixing calculated for such an alloy [200 kJ/g atom (Ref. 25)]. Instead we argue that, in fact, a coherent coupled mixture of Mg and Ti is formed. The hexagonal symmetry is confirmed by additional TEM plan-view measurements. A typical result measured on a 50 nm Mg$_{0.70}$Ti$_{0.30}$/5 nm Pd film is shown in Fig. 7(a). The reflections from the Pd cap layer (diffuse rings due to very small crystallites on the order of 5 nm) can easily be distinguished from those of the Mg$_{0.70}$Ti$_{0.30}$ film (well defined rings with individual spots due to crystallites on the order of 50 nm). The reflections from the film are consistent with a $P6_3/mmc$ structure (the same as for Mg and Ti) with lattice spacings ($a=3.11\ \text Å$, $c=4.98\ \text Å$) in close agreement with the XRD results.

After hydrogenation, we find a reflection at $2\theta=28.1^\circ$ for the $y=0.90$ sample, whereas for the $y=0.70$ sample the hydride peak appears at $2\theta=32.8^\circ$. The difference in peak position suggests a difference in structure of the hydride phase. We can clearly identify the peak at $2\theta=28.1^\circ$ as the (110) reflection of a rutile MgH$_2$ phase ($2\theta=27.91^\circ$ for pure MgH$_2$). The small shift can be due either to small Ti doping in MgH$_2$ or to strain in the thin film. On the other hand, the peak at $2\theta=32.8^\circ$ is more difficult to identify. We assume this hydride to have fcc symmetry (“fluorite” phase) as its peak position is close to the (111) reflection of fcc TiH$_2$ and almost coincides with high-pressure fcc MgH$_2$. Assuming a fluorite phase, the corresponding lattice spacing is $a=4.729\ \text Å$. TEM plan-view measurements on hydrogenated Mg$_{0.70}$Ti$_{0.30}$ films confirm the fcc symmetry [where the (111), (200), (220), (311), and (222) reflections can be identified] and indicate a structural homogeneity at least on a scale above 20 nm [Fig. 7(b)]. The lattice spacing obtained from these measurements is $a=4.55\ \text Å$. This value is slightly lower than the data obtained from XRD on similar compositions, indicating a partial dehydrogenation due to electron-beam bombardment during the TEM measurements.

The reflection at $2\theta=32.8^\circ$ is also close to the 222 reflection reported for the Mg$_2$TiH$_4$ phase (Ca$_3$Ge-type structure; $a=9.532\ \text Å$) synthesized in a high-pressure anvil cell by mixing MgH$_2$ and TiH$_1.9$ at 8 GPa and 873 K. The structure of this phase was argued to be similar with that of TiH$_{1.9}$ (fcc) but with most of the Ti atoms substituted by Mg in an or-
ordered way, resulting in a superstructure with a doubled unit cell.

As shown in Figs. 6(a) and 6(b), after full dehydrogenation, the peak shifts back to its initial position, which is evidence for the structural reversibility of the system and the absence of phase segregation. This is a surprising result since hydrogen cycling in Mg-based systems is in general accompanied by a large scale phase segregation.\textsuperscript{20,27} Also remarkable is the fact that the films remain crystalline during hydrogenation and subsequent dehydrogenation. However, the crystallinity of the films decreases upon hydrogen cycling. This has, however, little effect on the switching time and the electrical resistivity measurements. Results measured on a $y=0.70$ sample, the transformation between the initial and the hydrogenated state is almost continuous and fully reversible. The intermediate steps shown here are measured during H desorption. Assuming an hcp structure in the as-prepared state and fcc structure in the final state, the intermediate steps should reveal an hcp-fcc phase transformation. Upon H uptake, first the lattice expands continuously (steps 4–7). We define as the solid solution state the whole range of $2\theta$ values which are attained continuously starting from the metallic state. At intermediate hydrogen concentrations (step 3), the double-peak structure of the XRD spectrum points to coexistence of two phases: an fcc phase and an hcp phase. Subsequent H uptake leads to a further expansion of the fcc phase.

Similar intermediate steps can be defined for all compositions in the $0.55<y<0.95$ range. Interestingly, the minimum $2\theta$ angle in the metal solid solution phase is the same for all compositions and corresponds to the scattering angle of both TiH$_2$ (111 reflection) and Mg (002 reflection). This result strongly suggest a hydrogenation sequence where hydrogen first occupies Ti-related sites in the Mg-Ti lattice. An indication in favor of this scenario is also the increase in peak intensity in the beginning of the hydrogenation process. The lattice expands and becomes more ordered since the molar volume of TiH$_2$ (13.3 cm$^3$) equals almost exactly that of pure Mg (13.98 cm$^3$). The data in Fig. 6(d) also suggest that the amount of hydrogen that can be dissolved as a solid solution in the metal alloy phase increases with increasing Ti concentration.

Additional information on the phase composition of hydrogenated films is obtained from combined structural and electrical resistivity measurements. Results measured on a $y=0.70$ sample are shown in Fig. 8. In the beginning of the hydrogenation process, the electrical resistivity varies only slightly, while $2\theta$ decreases continuously, up to the solid solution state. An increase in electrical resistivity is measured only on further hydrogenation ($t>3000$ s), while $2\theta$ de-
creases further. However, for $t > 4000$ s, $2\theta$ remains constant, whereas the electrical resistivity varies almost by a factor of 2. This result suggests the presence of a noncrystalline component that takes up hydrogen. The origin of this phase is not yet clear. It could be related to x-ray amorphous material formed at grain boundaries. A precise estimate of the amount of this phase is rather difficult also because we cannot exclude the formation of crystalline material while the XRD peak remains at a constant position. Hence, the increase in resistivity could also be related to more and more crystalline hydrided material being formed. If we assume only a linear increase of electrical resistivity with hydrogen content and combine the results in Fig. 8 with hydrogen content measurements (see Fig. 5), we can estimate the maximum fraction of amorphous phase to be $\sim 45\%$ of the total for a $y = 0.70$ sample. This fraction is quite high and is probably overestimated since TEM plan-view measurements on as-prepared films do not show evidence of an amorphous phase. Very likely, the assumption of a linear increase of electrical resistivity with hydrogen content is too simplistic and possible; crystalline material is still being formed while the XRD peak remains at a constant position. Only on a hydrogen cycled sample, TEM cross-section images and XRD indicate clearly an increase in disorder in comparison to the as-prepared state.

IV. DISCUSSION

As suggested in the previous section, the formation of a Mg-Ti random alloy on deposition is very unlikely given the large positive enthalpy of mixing. The occurrence of a single hcp Bragg pattern is not sufficient to prove the alloy formation on an atomic scale$^{39,30}$ but it suggests a certain local order. The reversibility of the hydrogenation process suggests that this ordering remains intact on cycling. The optical and electrical data on fully hydrogenated films suggest the presence of an insulating MgH$_2$-like phase for all metal alloy compositions. Besides the insulating component, a second phase with a metallic character should be present to account for the highly absorbing state. For example, for a $y = 0.70$ sample, the volume fraction of the insulating component is $\sim 75\%$, corresponding thus to the entire Mg fraction in the metal alloy. In a $\text{Mg}_y\text{Ti}_{1-y}$ homogeneous random alloy, the amount of Mg$_4$ clusters (equal to $y^4$ assuming a binomial distribution) is only $\sim 24\%$, much lower than what is needed to explain the optical and electrical properties. Also on the basis of XRD data, large scale segregation is excluded. Clear structural indications of a rutile MgH$_2$ phase are found only for Mg-rich compositions ($y > 0.87$). For $y < 0.87$ compositions, the XRD data point to a structure with cubic symmetry and a lattice parameter that varies continuously with metal content in the parent alloy.

Recent theoretical calculations on $\text{Mg}_{0.75}\text{Ti}_{0.25}\text{H}_2$ (Ref. 31) structures with a cubic symmetry reveal a metallic character, in disagreement with our temperature dependent resistivity measurements and the optical data. From this and the continuous dependence of structure on metal alloy composition, we conclude that the $\text{Mg}_c\text{Ti}_{1-c}\text{H}_x$ films with $y < 0.87$ are neither single phase nor phase separated. Instead, the experimental evidence suggests the formation of insulating MgH$_2$ and metallic TiH$_2$ regions that form a coherent crystalline structure. This conclusion is consistent with a hydrogenation sequence where hydrogen first occupies Ti-related sites. A schematic representation of a coherent crystalline grain consisting of a Mg and Ti region is shown in Fig. 9(a).

The local deformation is only schematic and might deviate from reality. The same crystalline grain after hydrogen uptake in the Ti-related sites and in the fully hydrogenation state is shown in Figs. 9(b) and 9(c), respectively. This peculiar hydrogenation sequence is related to the more negative enthalpy of formation of TiH$_2$ ($\sim -70$ kJ/mol H) as compared to MgH$_2$ ($\sim -32$ kJ/mol H). Very likely, hydrogenation of Ti-related sites in the beginning of the hydrogenation process reduces the mobility of atoms during further hydrogen uptake and thus prevents the large scale segregation, observed in many other Mg-based systems.

In a scenario based on a coherent mixture of MgH$_2$ and TiH$_2$, the structural data for $y < 0.87$ compositions can be understood by assuming that both components have a cubic structure. This is expected for TiH$_2$. On the other hand, at normal pressures and temperatures, MgH$_2$ crystallizes in a...
rutile structure. A cubic MgH\(_2\) phase was reported to be formed only at high pressures (4 GPa).\(^\text{26}\) The theoretical calculations of Vajeeston et al.\(^\text{32}\) confirm a similar cubic phase as being the most stable structure if the unit-cell volume is reduced to 27.5 Å\(^3\)/f.u. (equivalent to \(a=4.79\) Å). The formation of a cubic MgH\(_2\) phase in our thin films, at normal pressures and temperatures, is not entirely clear. Very likely, it is related to the coherent coupling to Ti/TiH\(_2\) and the local stress induced. Using the pressure vs volume dependence calculated by Vajeeston et al.\(^\text{32}\) the lattice constant of cubic MgH\(_2\) at normal pressures should be \(a(\text{MgH}_2)=4.839\) Å. With this value, the average lattice spacing of fully hydrogenated Mg\(_y\)Ti\(_{1-y}\) films with \(y<0.80\) is well reproduced by the weighted average of the two components as follows

\[
a_{\text{Mg}_y\text{Ti}_{1-y}H_x} = y a_{\text{MgH}_2} + (1 - y) a_{\text{TiH}_2}.
\]

Then, on average, the hydrogen-to-metal ratio of the crystalline coherent structure is 2. This value corresponds to a higher hydrogen content than what we measured electrochemically ([H]/[M]=1.55), and therefore supports the conclusion that an x-ray amorphous component is present which reacts only partly with hydrogen. Since the optical data suggest a high fraction of insulating material, part of this amorphous component must be insulating with properties similar to those of MgH\(_2\). The rest is likely to remain metallic as unreacted or partially oxidized Mg and Ti. Very likely, this amorphous component does not play an active role in maintaining the coherence of the system.

Structural coherence was reported for several systems with positive energy of mixing, such as Ag-Cu,\(^\text{33}\) Cu-Cr,\(^\text{29}\) or Cu-Fe,\(^\text{34}\) but the mechanism responsible for this effect is still a subject of controversy.\(^\text{35-38}\) Experimental results from nanometer-resolution methods such as atom probe field ion microscopy\(^\text{30}\) or extended x-ray absorption fine structure could shed more light on the subject. It is though quite remarkable that in Mg-Ti, the coherent structure is preserved at all intermediate states during hydrogenation. This is likely to be related to the similarities in molar volume between Mg and TiH\(_2\).

Recently, the thermodynamic properties of Mg\(_y\)Ti\(_{1-y}\) thin films were studied with hydrogenography.\(^\text{39}\) In this method, the equilibrium pressure and the enthalpy of formation of Mg\(_y\)Ti\(_{1-y}\)H\(_x\) are determined by following the changes in optical transmission upon hydrogenation. In the 0.65\textless y \textless 0.90 range, the enthalpy of formation determined with this method does not depend significantly on composition and is similar to that of thin-film MgH\(_2\). Therefore, these results support our model that considers a coherent structure containing MgH\(_2\).

V. CONCLUSIONS

Hydrogenation of Mg\(_y\)Ti\(_{1-y}\) thin films prepared by co-sputtering of Mg and Ti is monitored continuously optically, electrically, and with x-ray diffraction. All the properties are found to depend on the metal ratio in the parent alloy. Structurally, as-prepared films show only one crystalline phase over a wide composition range (0.55\textless y \textless 0.95) that corresponds to a hexagonal Mg-Ti alloy. Hydrogenation induces a reversible phase transformation. The structure of the hydride depends on the metal ratio in the parent alloy. From XRD, the average structure resembles the rutile MgH\(_2\) phase for high Mg content samples (y > 0.90) and is fluorite otherwise (y < 0.87). At intermediate composition, coexistence of both phases is found. Highly reflective in the metallic state, the films are highly absorbing in the fully hydrogenated state (87% of the solar spectrum for Mg\(_{0.80}\)Ti\(_{0.20}\)H\(_2\)). Such a highly absorbing state hints at the coexistence of a metallic and a semiconducting phase. It is, however, not simply a composite material consisting of independent MgH\(_2\) and TiH\(_2\) grains. By continuously monitoring the structure during H uptake, we obtain data that are compatible with a coherent structure. The complete reversibility of the system and the structural coherence are probably related to the equality of the molar volumes of TiH\(_2\) and Mg. The present results point toward a rich and unexpected chemistry of Mg-Ti-H compounds.

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